

Features

- Multilayer Metal -Silicon Potential Structure
- High Current Capability, High Efficiency
- High Junction Temperature Capability
- Low Leakage Current
- Low forward voltage drop

Applications

- Surface mount schottky barrier rectifier
- Buck and Boost dc-dc Converters
- Low Voltage High Frequency Switching Power Supply
- Low Voltage High Frequency Invers Circuit
- Low Voltage Continued Circuit and Protection Circuit



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R, V_{RM}, V_{RWM}	40	V
Maximum RMS voltage	V_{RMS}	28	V
Forward Continuous Current	I_{FM}	2	A
Non-Repetitive Peak Forward Surge Current@t=8.3ms	I_{FSM}	80	A
Maximum instantaneous forward voltage at 2.0A	V_F	0.43	V
Typical Thermal Resistance per leg @TA = 25°C	$R_{\theta JA}$	75	°C/W
Operating Junction Temperature Range	T_J	125	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_F=30\mu A$	40	--	--	V
Reverse current	I_R	$V_R=40V$	--	20	100	μA
Forward voltage	V_F	$I_F=2A$	--	--	0.43	V
Total Capacitance	C_{tot}	$V_R = 0 V, f = 1 MHz$	--	450	--	pF

Typical Electrical Characteristic Curves

FIG. 1- FORWARD CURRENT DERATING CURVE

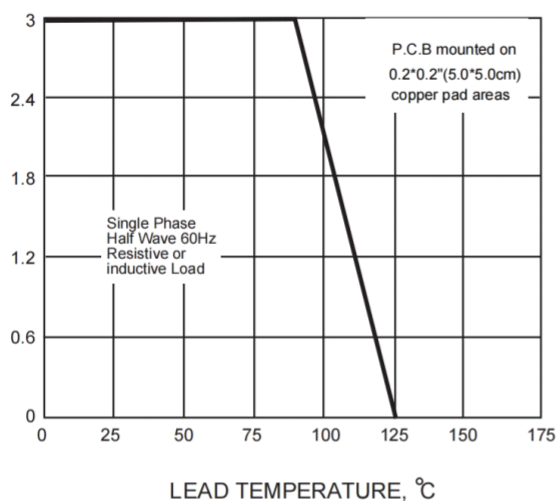


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

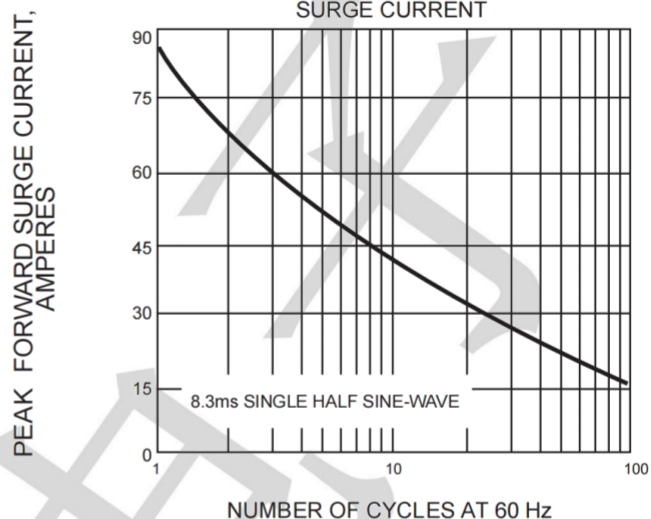


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

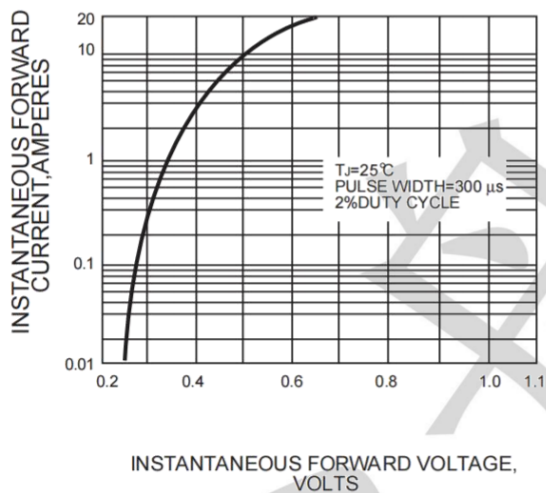


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

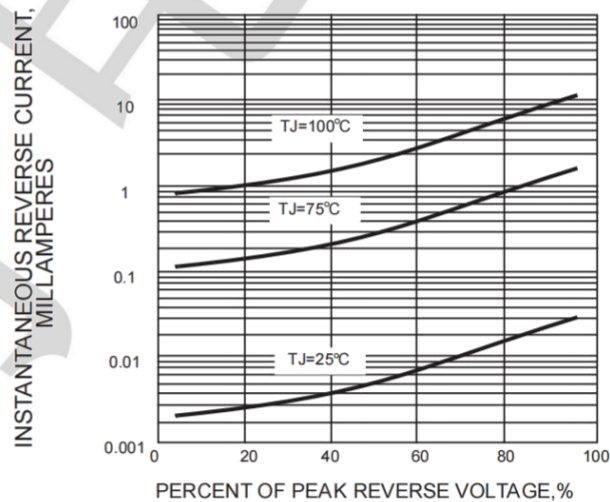


FIG. 5-TYPICAL JUNCTION CAPACITANCE

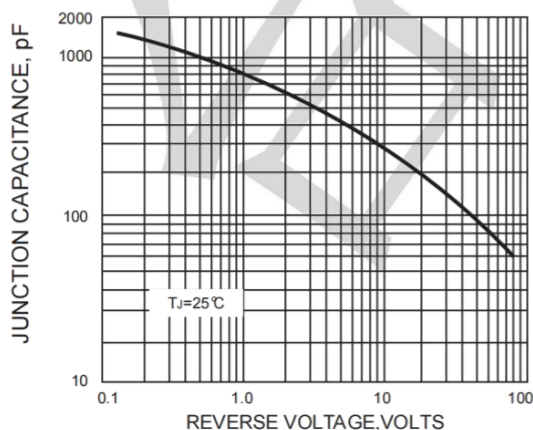
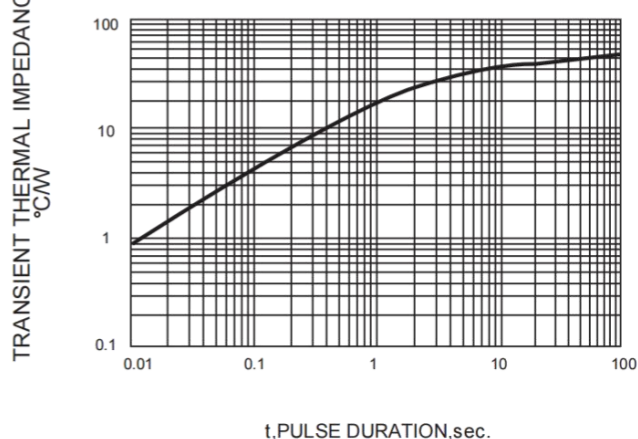
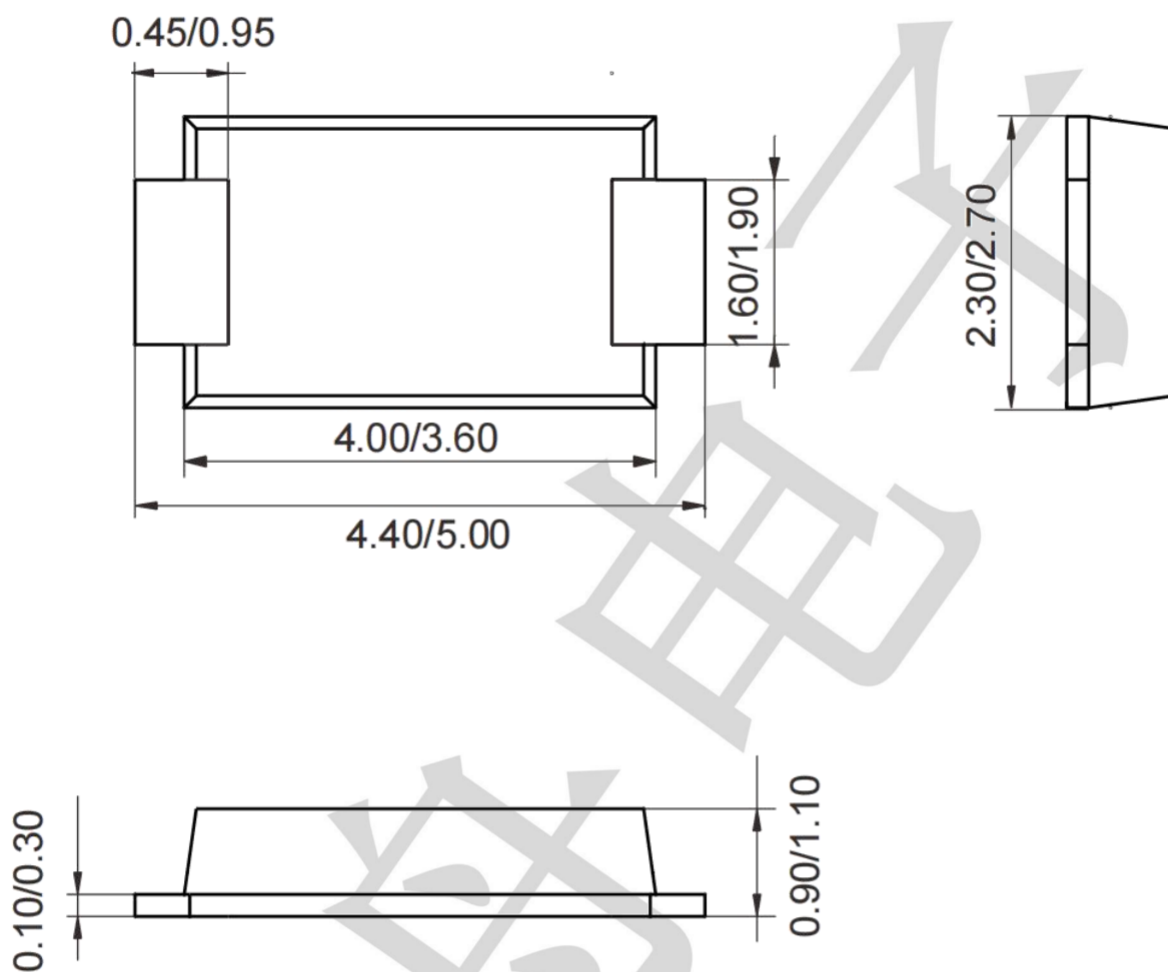


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



Package Outline Dimensions (unit: mm)

SOD128



Mounting Pad Layout (unit: mm)

